2N3054 2N3054A

DESCRIPTION

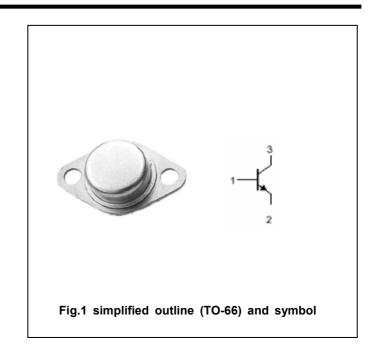
·With TO-66 package

APPLICATIONS

·Designed for general purpose switching and amplifier applications

PINNING (See Fig.2)

PIN	DESCRIPTION	
1	Base	
2	Emitter	
3	Collector	



Absolute maximum ratings(Ta=25□)

SYMBOL	PARAMETER		CONDITIONS	VALUE	UNIT
V_{CBO}	Collector-base voltage		Open emitter	90	V
V _{CEO}	Collector-emitter voltage		Open base	55	V
V _{EBO}	Emitter-base voltage		Open collector	7	V
Ic	Collector current			4	А
I _B	Base current			2	Α
P_D	Power dissipation	2N3054	T _C =25□	25	W
		2N3054A		75	VV
T _j	Junction temperature			200	
T_{stg}	Storage temperature			-65~200	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER		MAX	UNIT	
R _{th j-C}	Thermal resistance junction to case	2N3054	7.0		
		2N3054A	2.33	· □/W	

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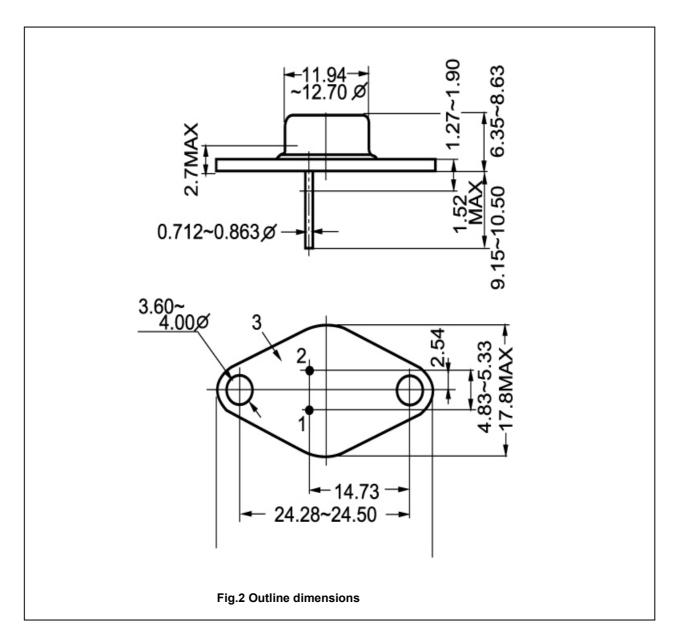
CHARACTERISTICS

Tj=25□ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CEO}	Collector-emitter breakdown voltage	I _C =0.1A; I _B =0	55			V
V _{CEsat-1}	Collector-emitter saturation voltage	I _C =0.5A ;I _B =50mA			1.0	V
V _{CEsat-2}	Collector-emitter saturation voltage	I _C =3A; I _B =1A			6.0	V
V_{BE}	Base -emitter on voltage	I _C =0.5A ; V _{CE} =4V			1.7	V
I _{CEV}	Collector cut-off current	V _{CE} =90V;V _{BE(off)} =1.5V T _C =150□			1.0 6.0	mA
I _{CEO}	Collector cut-off current	V _{CE} =30V; I _B =0			0.5	mA
I _{EBO}	Emitter cut-off current	V _{EB} =7V; I _C =0			1.0	mA
h _{FE-1}	DC current gain	I _C =0.1A; V _{CE} =10V	40			
h _{FE-2}	DC current gain	I _C =1A; V _{CE} =2V	8		80	
f _T	Transition frequency	I _C =0.2A ; V _{CE} =10V;f=1MHz	3.0			

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PACKAGE OUTLINE



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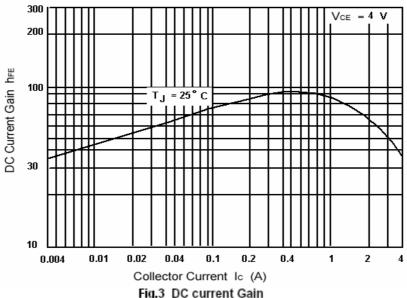


Fig.3 DC current Gain 1.0 $I_{C}/I_{B} = 10$ Collector Saturation Voltage VcE(sat) (V) 0.8 Base Saturation Voltage VBE(sat) (V) 0.6 V_{BE} (sat) 0.4 0.2 c 0.02 0.04 2 0.004 0.01 0.1 0.2 0.4 Collector Current Ic (A)

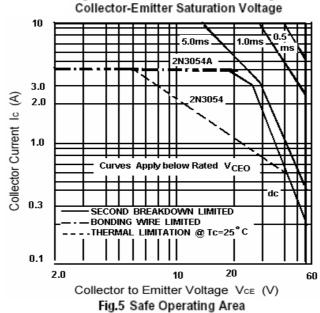


Fig.4Base-Emitter Saturation Voltage